

11V Input 150mA LDO

NO.EA-256-111020

OUTLINE

The RP173x Series are CMOS-based voltage regulator ICs featuring 150 mA output and low supply current of Typ.2.0 μ A. Each of these ICs consists of a voltage reference unit, an error amplifier, a resistor-net for voltage setting, a current limit circuit, a chip enable circuit and a Reverse Current Protection Circuit. RP173x Series are suitable for the power source such as the equipment being in the standby-mode. A version with /CE input pin has reduced CE pull-up resistance to make its supply current ultra low.

The RP173x Series have Max.11V Input voltage and are applicable to the portable communication equipment that require the 2-cell Li-ion battery. Also they are applicable to the non-portable communication equipments. As this series includes Reverse Current Protection Circuit, there is little leakage current, if it's used as back-up circuit.

Since the packages for these ICs are the SOT-23-5 package, SC-88A, or DFN(PLP)1010-4 of 1mm square, high density mounting of the ICs on boards is possible.

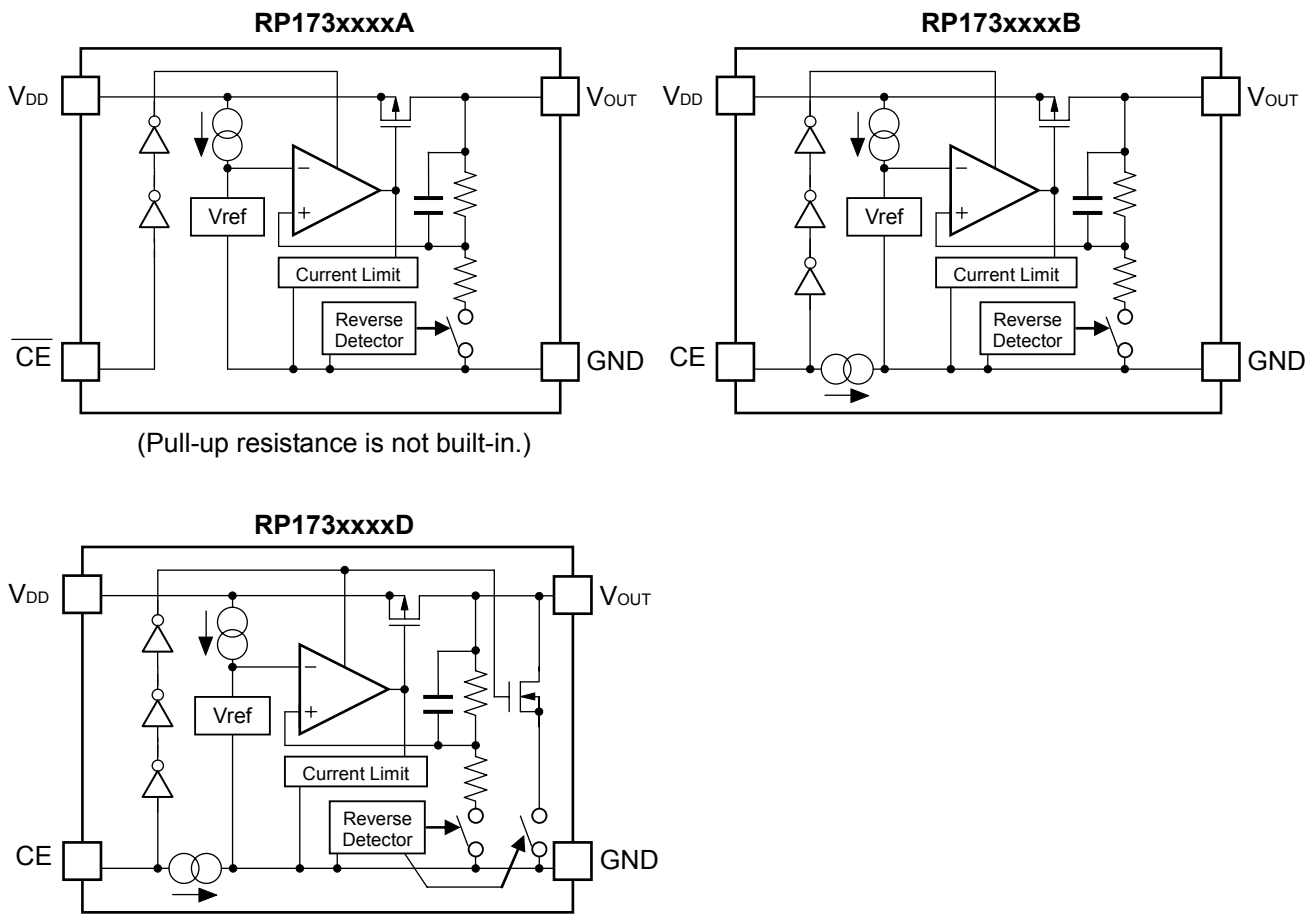
FEATURES

- Output Current Typ. 150mA
- Supply Current Typ. 2.0 μ A
- Standby Current Typ. 0.2 μ A
- Input Voltage Range 2.5V to Set $V_{OUT}+6.5V$ (Max.11V)
- Output Voltage Range..... 1.2V to 5.5V (0.1V steps)
(For other voltages, please refer to MARK INFORMATION.)
- Dropout Voltage Typ. 0.13V ($I_{OUT}=30mA$, $V_{OUT}=3.0V$)
Typ. 0.90V ($I_{OUT}=150mA$, $V_{OUT}=3.0V$)
- Output Voltage Accuracy..... $\pm 1.0\%$ ($1.5V < V_{OUT} \leq 5.5V$, $T_{opt}=25^{\circ}C$)
- Temperature-drift Coefficient of Output Voltage..... Typ. $\pm 100ppm/^{\circ}C$
- Line Regulation Typ. 0.02%/V
- Packages DFN(PLP)1010-4, SC-88A, SOT-23-5
- Built-in Reverse Current Protection Circuit
- Short Current Limit Typ. 45mA
- Built-in Peak Current Limit Circuit
- Output capacitors 0.1 μ F or more

APPLICATIONS

- Power source for portable communication equipments.
- Power source for battery-powered equipments.
- Power source for electrical appliances such as cameras, VSRs and camcorders.
- Power source for digital home appliances.

BLOCK DIAGRAMS



SELECTION GUIDE

The output voltage, auto discharge function, package for the ICs can be selected at the user's request.

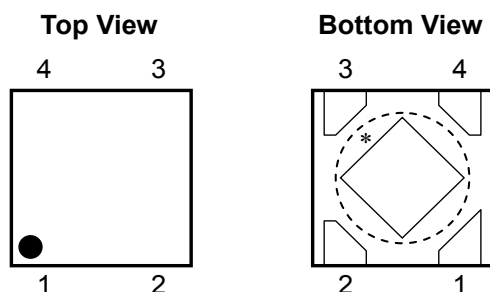
Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP173Kxx1*-TR	DFN(PLP)1010-4	10,000 pcs	Yes	Yes
RP173Qxx2*-TR-FE	SC-88A	3,000 pcs	Yes	Yes
RP173Nxx1*-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes

xx: The output voltage can be designated in the range of 1.2V (12) to 5.5V (55) in 0.1V steps.
(For other voltages, please refer to MARK INFORMATIONs.)

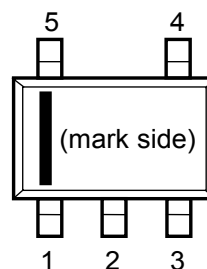
* : The auto discharge function at off state are options as follows.
(A) "L" active, without auto discharge function at off state (Pull-up resistance is not built-in.)
(B) "H" active, without auto discharge function at off state
(D) "H" active, with auto discharge function at off state

PIN CONFIGURATIONS

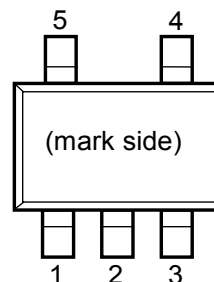
● DFN(PLP)1010-4



● SC-88A



● SOT-23-5



PIN DESCRIPTIONS

● DFN(PLP)1010-4

Pin No.	Symbol	Description
1	V_{OUT}	Output Pin
2	GND	Ground Pin
3	$\overline{CE}$ /CE	Chip Enable Pin
4	V_{DD}	Input Pin

*) Tab is GND level. (They are connected to the reverse side of this IC.)

The tab is better to be connected to the GND, but leaving it open is also acceptable.

● SC-88A

Pin No.	Symbol	Description
1	$\overline{CE}$ /CE	Chip Enable Pin
2	NC	No Connection
3	GND	Ground Pin
4	V_{OUT}	Output Pin
5	V_{DD}	Input Pin

● SOT-23-5

Pin No.	Symbol	Description
1	V_{DD}	Input Pin
2	GND	Ground Pin
3	$\overline{CE}$ /CE	Chip Enable Pin
4	NC	No Connection
5	V_{OUT}	Output Pin

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	12	V
V_{CE}	Input Voltage (CE pin)	12	V
V_{OUT}	Output Voltage	−0.3 to 6.0	V
I_{OUT}	Output Current	165	mA
P_D	Power Dissipation (DFN(PLP)1010-4)*	400	mW
	Power Dissipation (SC-88A)*	380	
	Power Dissipation (SOT-23-5)*	420	
T_{opt}	Operating Temperature Range	−40 to +85	°C
T_{stg}	Storage Temperature Range	−55 to +125	°C

*) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

ELECTRICAL CHARACTERISTICS

Unless otherwise noted, $V_{IN} = \text{Set } V_{OUT} + 1.0V (V_{OUT} > 1.5)$, $I_{OUT} = 1mA$, $C_{IN} = C_{OUT} = 0.1\mu F$.

The values in are applicable under the condition of $-40^{\circ}C \leq T_{opt} \leq 85^{\circ}C$.

● RP173xxxxA

$T_{opt} = 25^{\circ}C$

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{OUT}	Output Voltage	$T_{opt} = 25^{\circ}C$	$V_{OUT} > 1.5V$	$\times 0.99$	$\times 1.01$	V
			$V_{OUT} \leq 1.5V$	-15	15	mV
		$-40^{\circ}C \leq T_{opt} \leq 85^{\circ}C$	$V_{OUT} > 1.5V$	$\times 0.982$	$\times 1.018$	V
			$V_{OUT} \leq 1.5V$	-28	27	mV
I_{OUT}	Output Current		150			mA
$\Delta V_{OUT} / \Delta I_{OUT}$	Load Regulation	$0.1mA \leq I_{OUT} \leq 150mA$	-30	-3	35	mV
V_{DIF}	Dropout Voltage	Refer to the "Dropout Voltage"				
I_{SS}	Supply Current	$I_{OUT} = 0mA$		2.0	3.7	μA
$I_{standby}$	Standby Current	$V_{IN} = V_{IN}(\text{Max.})$ $V_{CE} = 0V$		0.2	0.6	μA
$\Delta V_{OUT} / \Delta V_{IN}$	Load Regulation	Set $V_{OUT} + 0.5V \leq V_{IN} \leq V_{IN}(\text{Max.})$ When $V_{OUT} \leq 2.0V$, $2.5V \leq V_{IN} \leq V_{IN}(\text{Max.})$		0.02	0.20	%/V
RR	Ripple Rejection	$f = 1kHz$, Ripple $0.2Vp-p$, $I_{OUT} = 10mA$ ※ When $V_{OUT} < 2.0V$, $V_{IN} = 3.0V$		30		dB
V_{IN}	Input Voltage	$1.2 \leq V_{OUT} < 4.5$	2.5		$V_{set} + 6.5$	V
		$4.5 \leq V_{OUT} \leq 5.5$	2.5		11	
$\Delta V_{OUT} / \Delta T_{opt}$	Output Voltage Temperature Coefficient	$-40^{\circ}C \leq T_{opt} \leq 85^{\circ}C$		± 100		ppm/ $^{\circ}C$
I_{SC}	Short Current Limit Circuit	$V_{OUT} = 0V$		45		mA
V_{CEH}	$\overline{CE}$ Input Voltage "H"		1.7			V
V_{CEL}	$\overline{CE}$ Input Voltage "L"				0.8	V
I_{REV}	Reverse Current	$0 \leq V_{IN} \leq 11.0V$, $V_{OUT} \geq 1.5V$		0	0.16	μA
$V_{REV_DET}^*$	Reverse Current Protection Mode Detection Offset, $V_{REV} = V_{DD} - V_{OUT}$	$0 \leq V_{IN} \leq 11.0V$, $V_{OUT} \geq 1.5V$		55	100	mV
$V_{REV_REL}^*$	Reverse Current Protection Mode Release Offset	$0 \leq V_{IN} \leq 11.0V$, $V_{OUT} \geq 1.5V$		70	120	mV

The values in have been tested and guaranteed by Design Engineering.

All of units are tested and specified under the pulse load conditions such that $T_j \approx T_{opt} \pm 25^{\circ}C$ except for Ripple Rejection and Output Voltage Temperature Coefficient.

*) The operation coverage of the Reverse Current Protection Circuit is $V_{OUT} \geq 1.5V$. However, under the condition of $V_{IN} = V_{OUT} = 0V$, always the Reverse Current Protection Circuit is operating.

RP173x

Unless otherwise noted, $V_{IN} = \text{Set } V_{OUT} + 1.0V (V_{OUT} > 1.5)$, $I_{OUT} = 1mA$, $C_{IN} = C_{OUT} = 0.1\mu F$.

The values in are applicable under the condition of $-40^{\circ}C \leq T_{opt} \leq 85^{\circ}C$.

• RP173xxxxB/D

$T_{opt} = 25^{\circ}C$

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V_{OUT}	Output Voltage	$T_{opt} = 25^{\circ}C$	$V_{OUT} > 1.5V$	$\times 0.99$	$\times 1.01$	V
			$V_{OUT} \leq 1.5V$	-15	15	mV
		$-40^{\circ}C \leq T_{opt} \leq 85^{\circ}C$	$V_{OUT} > 1.5V$	$\times 0.982$	$\times 1.018$	V
			$V_{OUT} \leq 1.5V$	-28	27	mV
I_{OUT}	Output Current		150			mA
$\Delta V_{OUT}/\Delta I_{OUT}$	Load Regulation	$0.1mA \leq I_{OUT} \leq 150mA$	-30	-3	35	mV
V_{DIF}	Dropout Voltage	Refer to the "Dropout Voltage"				
I_{SS}	Supply Current	$I_{OUT} = 0mA$		2.0	3.7	μA
$I_{standby}$	Standby Current	$V_{IN} = V_{IN_Max}$ $V_{CE} = 0V$		0.2	0.6	μA
$\Delta V_{OUT}/\Delta V_{IN}$	Load Regulation	Set $V_{OUT} + 0.5V \leq V_{IN} \leq V_{IN_Max}$. When $V_{OUT} \leq 2.0V$, $2.5V \leq V_{IN} \leq \text{Set } V_{OUT} + 6.5V$		0.02	0.20	%/V
RR	Ripple Rejection	$f = 1kHz$, Ripple $0.2Vp-p$, $I_{OUT} = 10mA$ ※When $V_{OUT} < 2.0V$, $V_{IN} = 3.0V$		30		dB
V_{IN}	Input Voltage	$1.2 \leq V_{OUT} < 4.5$	2.5		$V_{set} + 6.5$	V
		$4.5 \leq V_{OUT} \leq 5.5$	2.5		11	
$\Delta V_{OUT}/\Delta T_{opt}$	Output Voltage Temperature Coefficient	$-40^{\circ}C \leq T_{opt} \leq 85^{\circ}C$		± 100		ppm/ $^{\circ}C$
I_{SC}	Short Current Limit Circuit	$V_{OUT} = 0V$		45		mA
I_{PD}	CE Pull-down Current			0.30	0.90	μA
V_{CEH}	CE Input Voltage "H"		1.7			V
V_{CEL}	CE Input Voltage "L"				0.8	V
I_{REV}	Reverse Current	$0 \leq V_{IN} \leq 11.0V$, $V_{OUT} \geq 1.5V$		0	0.16	μA
$V_{REV_DET}^*$	Reverse Current Protection Mode Detection Offset, $V_{REV} = V_{DD} - V_{OUT}$	$0 \leq V_{IN} \leq 11.0V$, $V_{OUT} \geq 1.5V$		55	100	mV
$V_{REV_REL}^*$	Reverse Current Protection Mode Release Offset	$0 \leq V_{IN} \leq 11.0V$, $V_{OUT} \geq 1.5V$		70	120	mV
R_{LOW}	Autodischarge Nch Tr. ON Resistance (D Version only)	$V_{IN} = 7.0V$, $V_{CE} = 0V$		380		Ω

The values in have been tested and guaranteed by Design Engineering.

All of units are tested and specified under the pulse load conditions such that $T_j \approx T_{opt} = 25^{\circ}C$ except for Ripple Rejection and Output Voltage Temperature Coefficient.

*) The operation coverage of the Reverse Current Protection Circuit is $V_{OUT} \geq 1.5V$. However, under the condition of $V_{IN} = V_{OUT} = 0V$, always the Reverse Current Protection Circuit is operating.

• Dropout Voltage

$T_{opt}=25^{\circ}\text{C}$

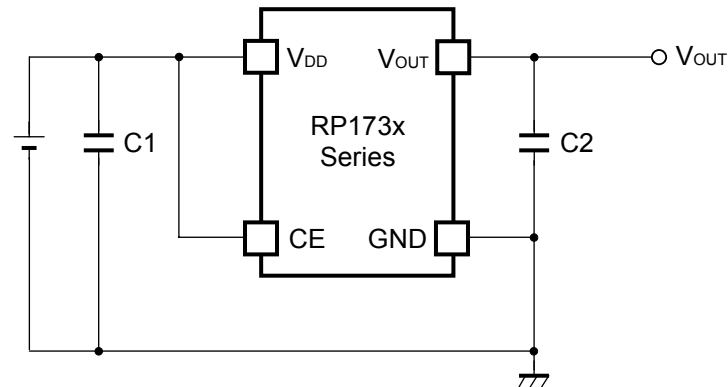
Output Voltage V_{OUT} (V)	Dropout Voltage V_{DIF} (V)		
	Condition	Typ.	Max.
$1.2 \leq V_{OUT} < 1.3$	$I_{OUT}=150\text{mA}$	1.68	2.59
$1.3 \leq V_{OUT} < 1.5$		1.63	2.49
$1.5 \leq V_{OUT} < 1.8$		1.48	2.23
$1.8 \leq V_{OUT} < 2.3$		1.16	2.19
$2.3 \leq V_{OUT} < 3.0$		0.90	1.47
$3.0 \leq V_{OUT} < 4.0$		0.61	1.05
$4.0 \leq V_{OUT} \leq 5.5$		0.39	0.76

The values in are applicable under the condition of $-40^{\circ}\text{C} \leq T_{opt} \leq 85^{\circ}\text{C}$.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

TYPICAL APPLICATIONS



External Parts Example:

C2: Ceramic Capacitor 0.1 μ F, Murata, GRM155B31C104KA87D

TECHNICAL NOTES

When using the ICs, please note the following points.

Phase Compensation

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a 0.1 μ F or more capacitor C2.

In case of using a tantalum capacitor, the output may be unstable due to inappropriate ESR. Therefore, the full range of operating conditions for the capacitor in the application should be considered.

PCB Layout

Make V_{DD} and GND lines sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect a capacitor C1 with a capacitance value as much as 0.1 μ F or more between V_{DD} and GND pin, and as close as possible to the pins.

Set external components, especially the output capacitor C2, as close as possible to the ICs, and make wiring as short as possible.

POWER ACTIVATION

If the ICs are started up with V_{IN} and V_{CE} under the no-load condition, the both pin voltages have to be started up with faster than 2.0V/s. If the IC is started up with slower than 2.0V/s under the no-load condition, start up the IC only with V_{CE} .

REVERSE CURRENT PROTECTION CIRCUIT

The RP173 Series include a Reverse Current Protection Circuit, which stops the reverse current from V_{OUT} pin to V_{DD} pin or to GND pin when V_{OUT} becomes higher than V_{IN} .

Usually, the LDO using Pch output transistor contains a parasitic diode between V_{DD} pin and V_{OUT} pin. Therefore, if V_{OUT} is higher than V_{IN} , the parasitic diode becomes forward direction. As a result, the current flows from V_{OUT} pin to V_{DD} pin.

The ICs of this series switches the mode to the reverse current protection mode before V_{IN} becomes lower than V_{OUT} by connecting the parasitic diode of Pch output transistor to the backward direction, and connecting the gate to V_{OUT} pin. As a result, the Pch output transistor is turned off and the all the current pathways from V_{OUT} pin to GND pin are shut down to maintain the reverse current lower than $[I_{REV}]$ of the Electrical Characteristics.

Switching to either the normal mode or to the reverse current protection mode is determined by the magnitude of V_{IN} voltage and V_{OUT} voltage. For the stable operation, offset and hysteresis are set as the threshold. The detection/ release thresholds of both normal and reverse current protection modes are specified by $[V_{REV_DET}]$ and $[V_{REV_REL}]$ of the Electrical Characteristics. Therefore, the minimum dropout voltage under the small load current condition is restricted by the value of $[V_{REV_REL}]$.

Fig.1 and Fig.2 show the diagrams of each mode, and Fig.3 shows the load characteristics of each mode. When giving the V_{OUT} pin a constant-voltage and decreasing the V_{IN} voltage, the dropout voltage will become lower than the $[V_{REV_DET}]$. As a result, the reverse current protection starts to function to stop the load current. By increasing the dropout voltage higher than the $[V_{REV_REL}]$, the protection mode will be released to let the load current to flow. If the dropout voltage to be used is lower than $[V_{REV_REL}]$, the detection and the release may be repeated.

The operation coverage of the Reverse Current Protection Circuit is $V_{OUT} \geq 1.5V$. However, under the condition of $V_{IN}=0V$, always the reverse current protection mode is operating.

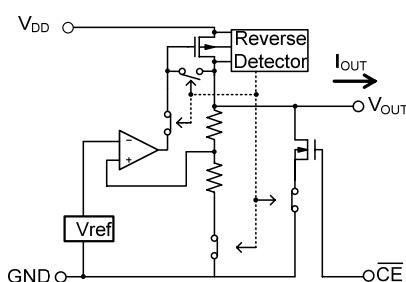


Fig. 1 Normal Mode

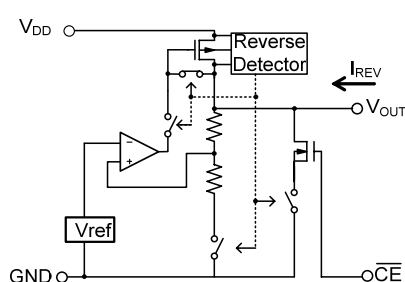


Fig. 2 Reverse Current Protection Mode

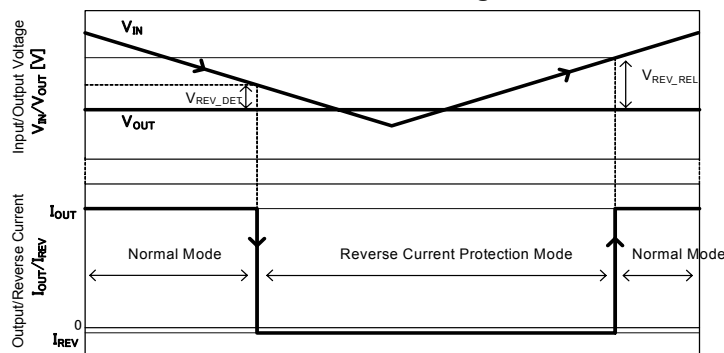
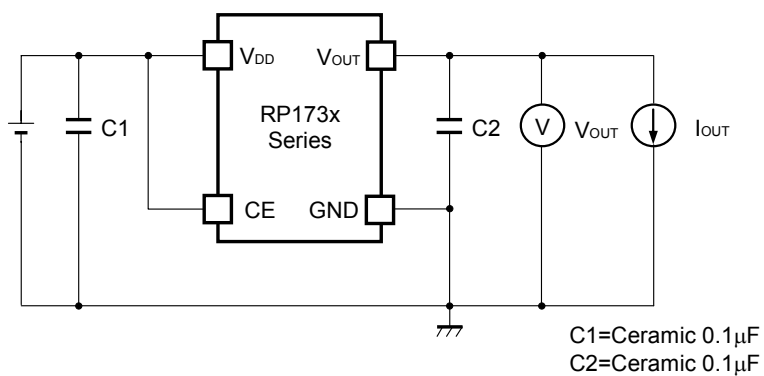
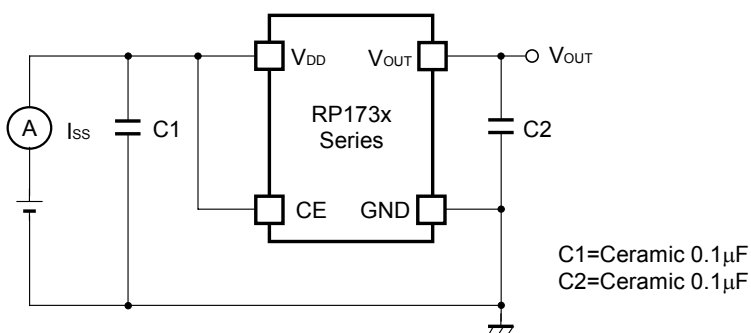


Fig. 3 Reverse Current Protection Mode Detection/Release & Reverse Current/Output Current Characteristics

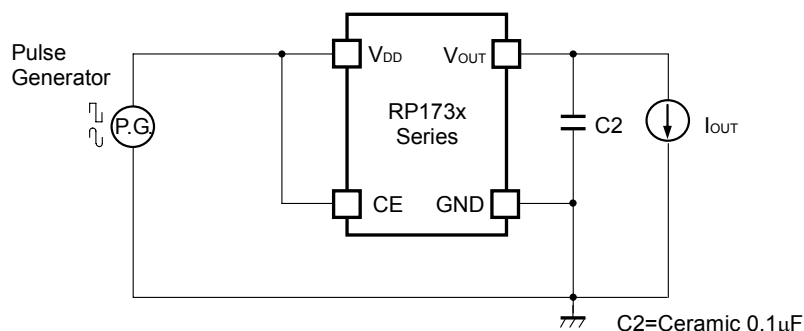
TEST CIRCUITS



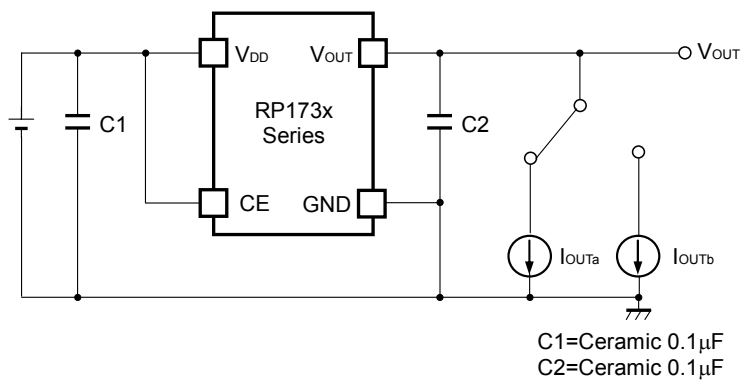
Basic Test Circuit



Supply Current Test Circuit



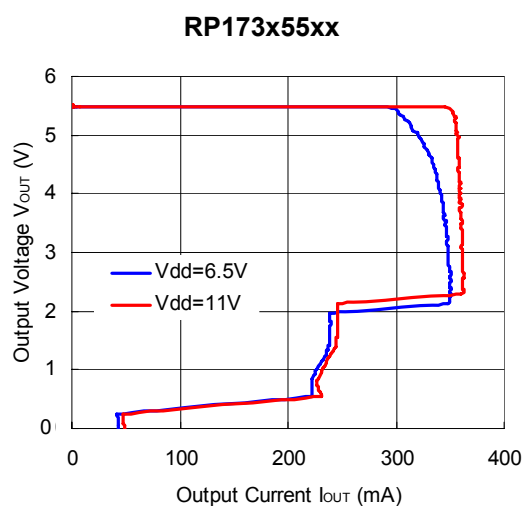
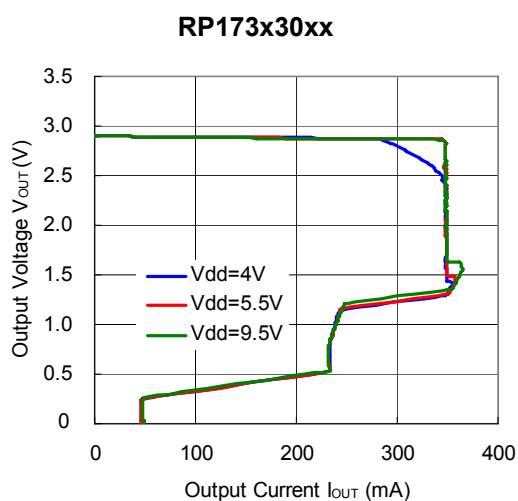
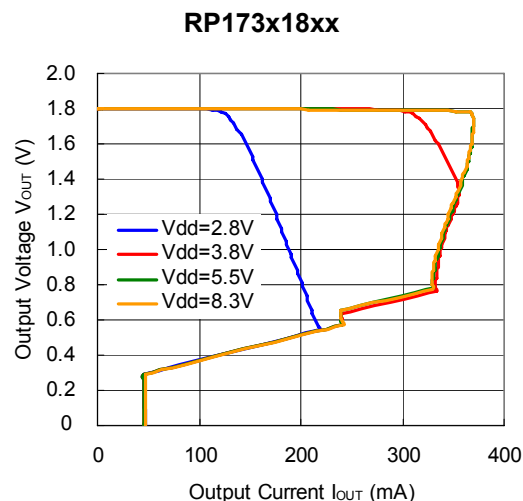
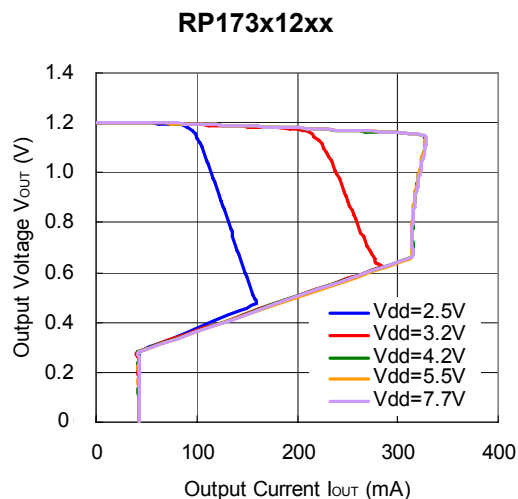
Ripple Rejection Test Circuit



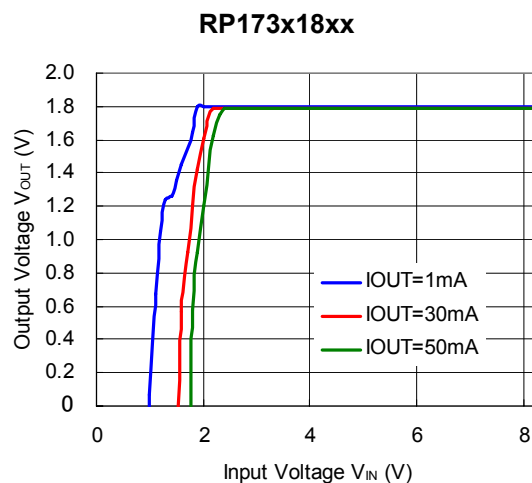
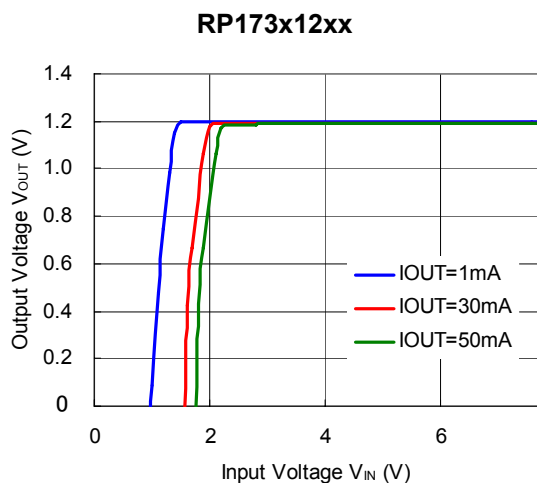
Load Transient Response Test Circuit

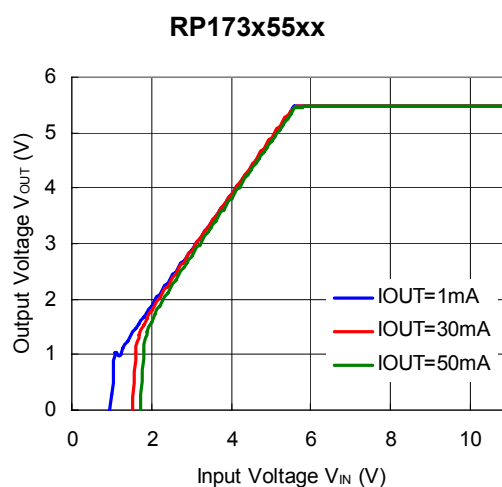
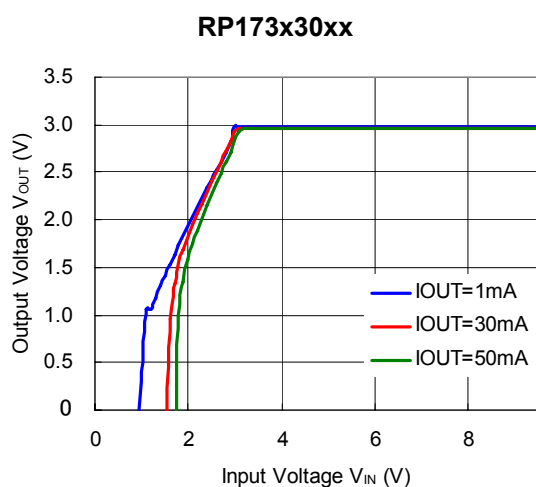
TYPICAL CHARACTERISTICS

1) Output Voltage vs. Output Current (C_1 =Ceramic 0.1 μ F, C_2 =Ceramic 0.1 μ F, T_{opt} =25°C)

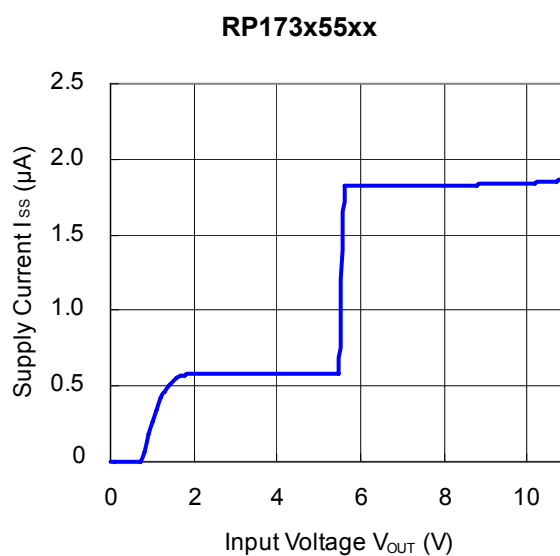
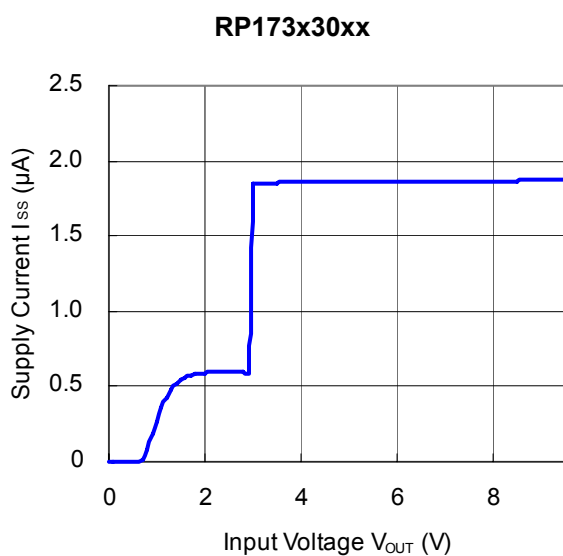
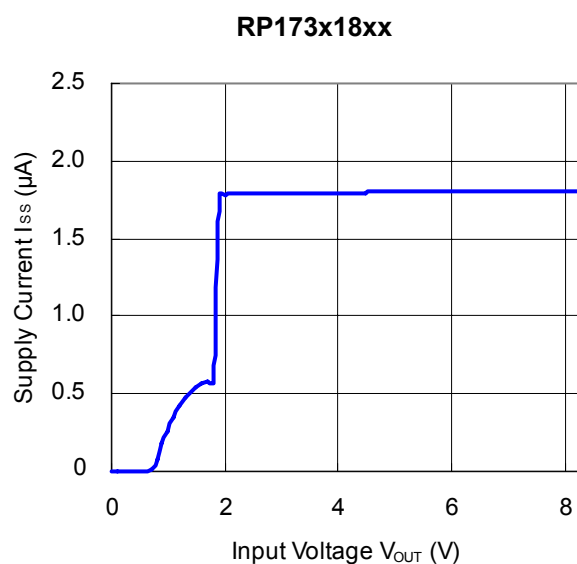
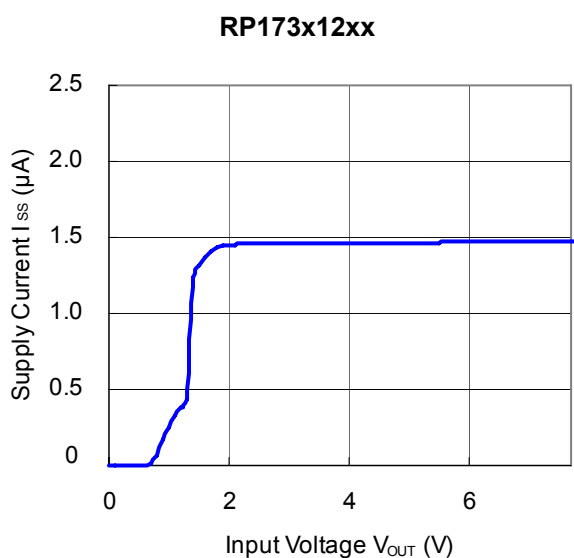


2) Output Voltage vs. Input Voltage (C_1 =Ceramic 0.1 μ F, C_2 =Ceramic 0.1 μ F, T_{opt} =25°C)

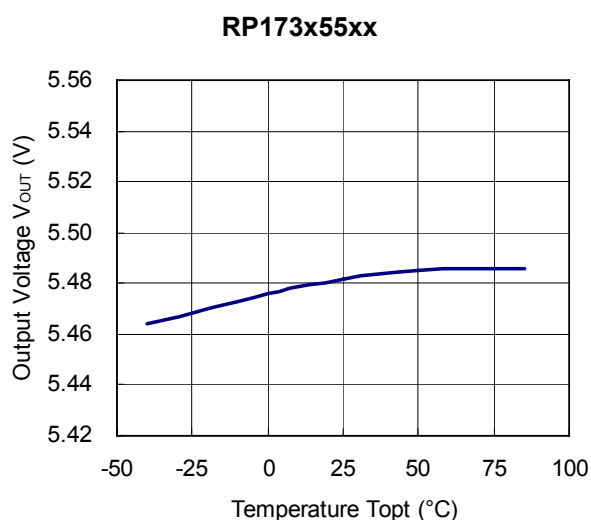
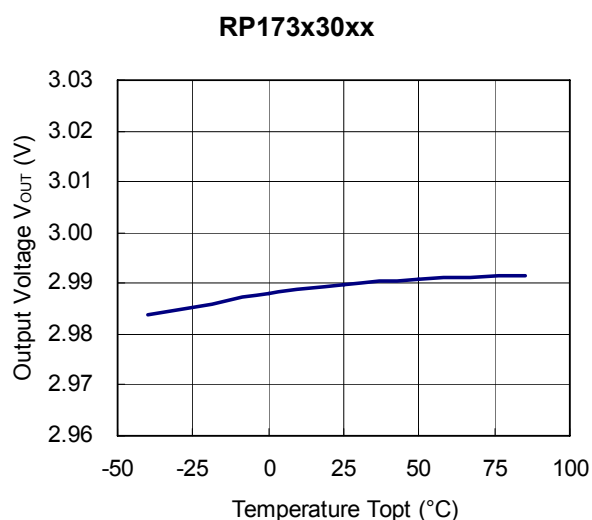
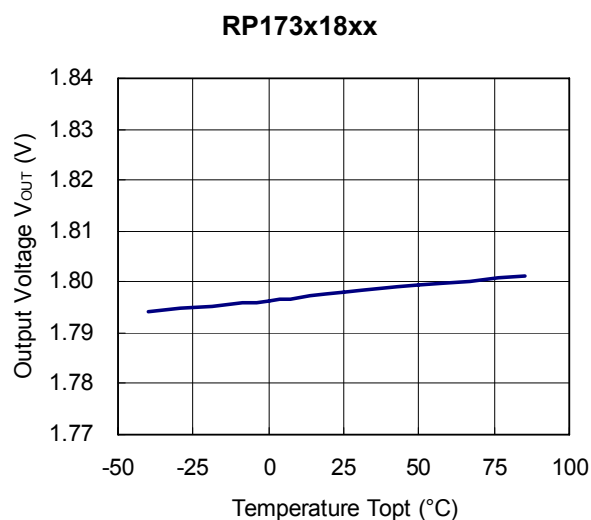
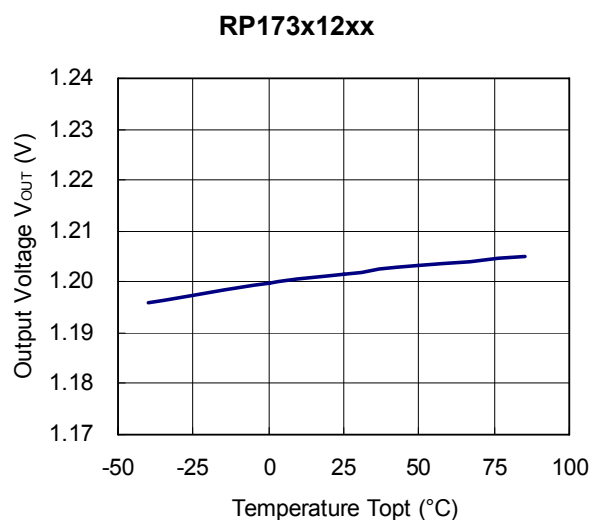




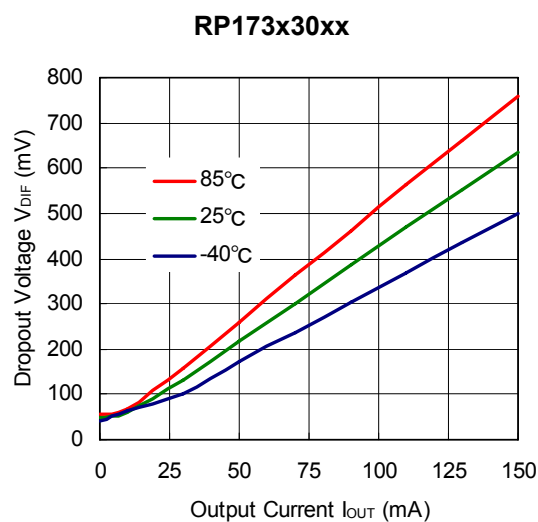
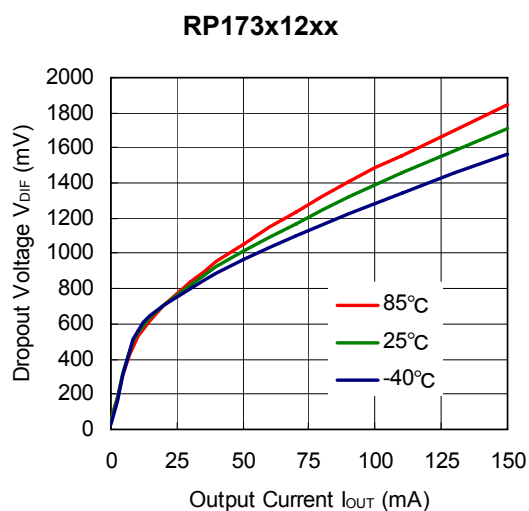
3) Supply Current vs. Input Voltage ($C1$ =Ceramic $0.1\mu F$, $C2$ =Ceramic $0.1\mu F$, $T_{opt}=25^{\circ}C$)

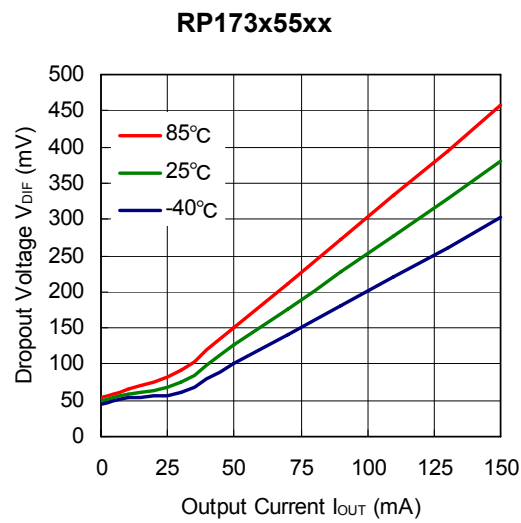


4) Output Voltage vs. Temperature (C1=Ceramic 0.1 μ F, C2=Ceramic 0.1 μ F, I_{OUT}=1mA)



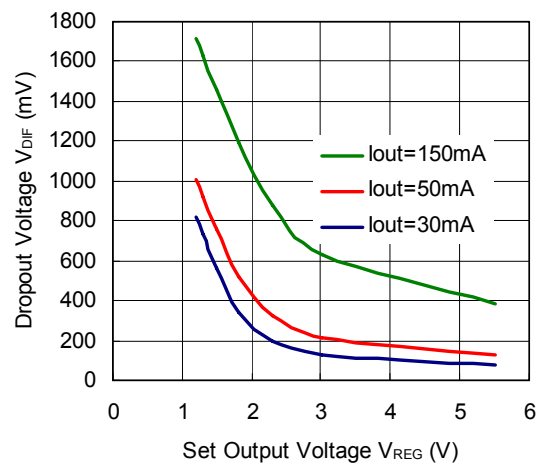
5) Dropout Voltage vs. Output Current (C1=Ceramic 0.1 μ F, C2=Ceramic 0.1 μ F)



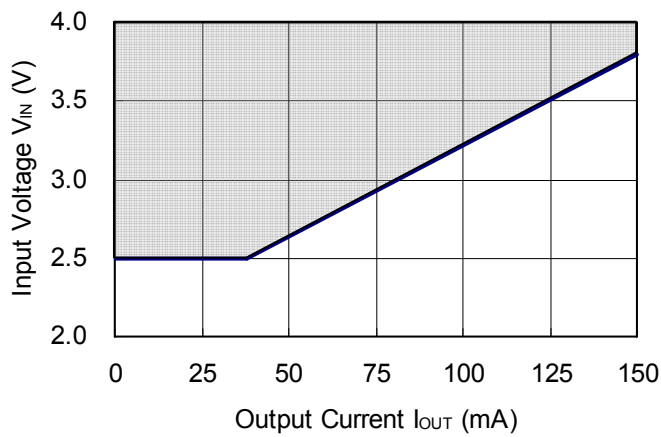


6) Dropout Voltage vs. Set Output Voltage (C1=Ceramic 0.1μF, C2=Ceramic 0.1μF, T_{opt}=25°C)

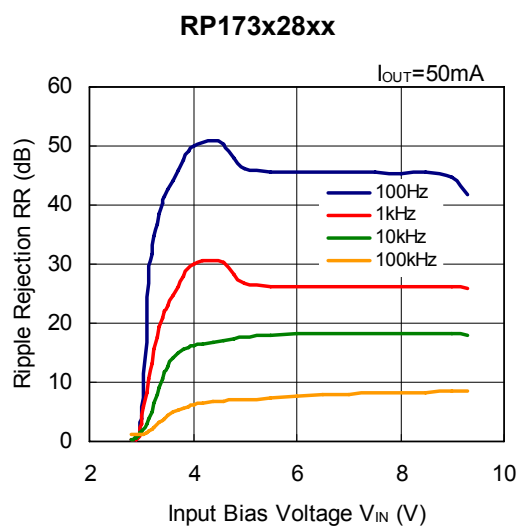
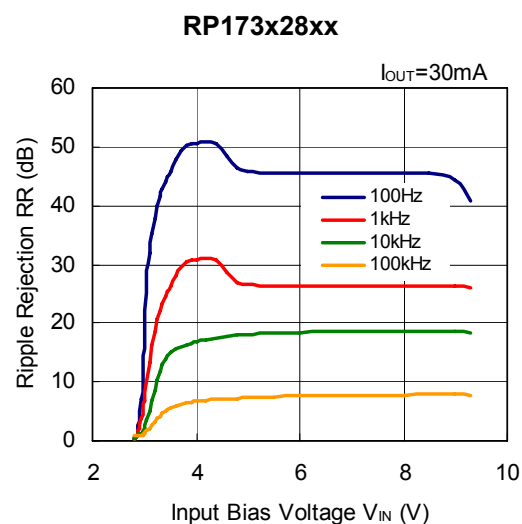
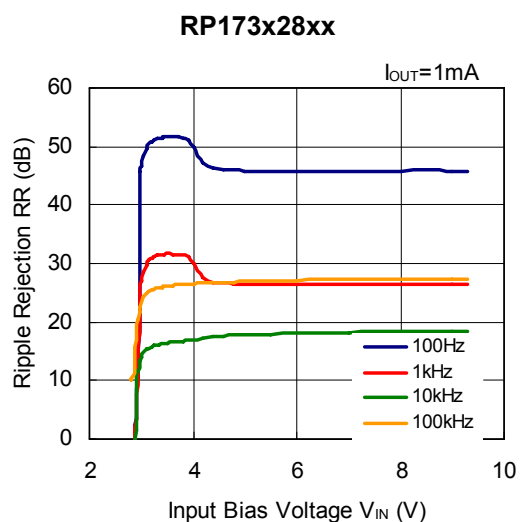
RP173x



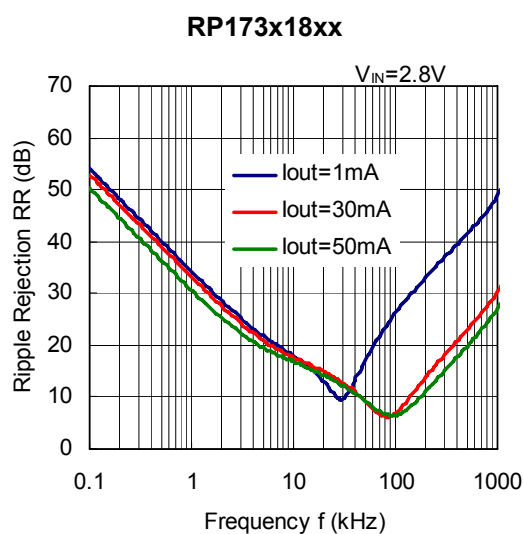
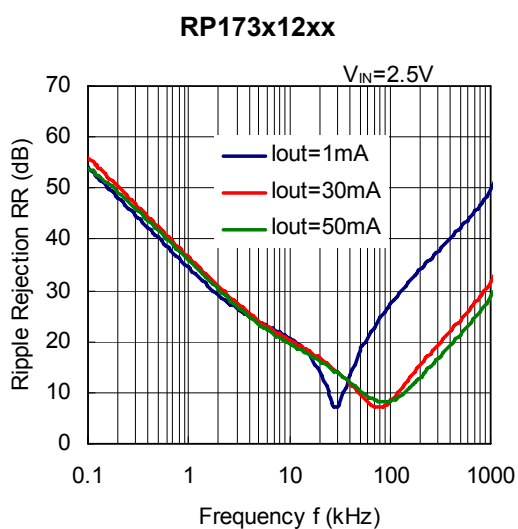
7) Minimum Operating Voltage (C1=Ceramic 0.1μF, C2=Ceramic 0.1μF, T_{opt}=-40~85°C)



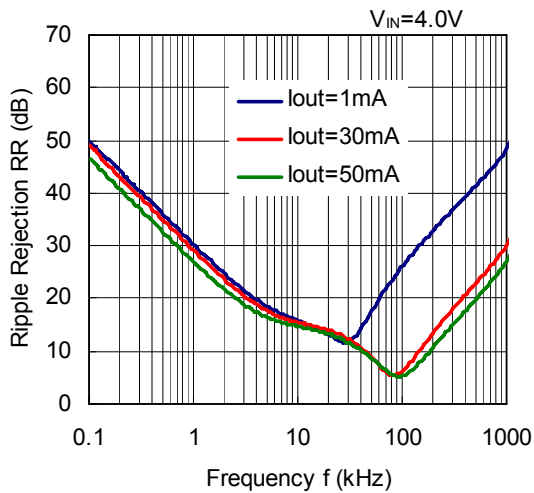
8) Ripple Rejection vs. Input Bias Voltage (C_1 =none, C_2 =Ceramic $0.1\mu\text{F}$, Ripple= 0.2Vp-p , $T_{\text{opt}}=25^\circ\text{C}$)



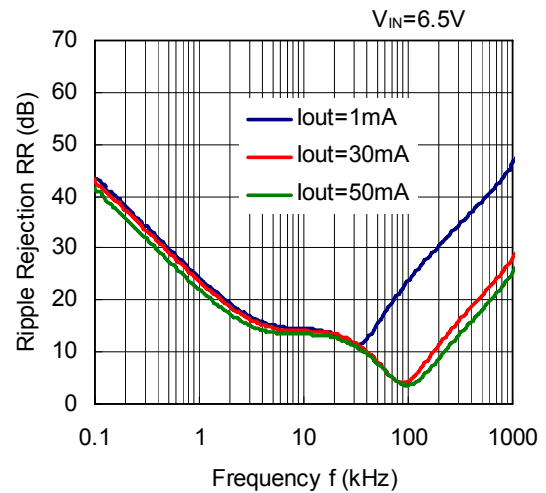
9) Ripple Rejection vs. Temperature (C_1 =none, C_2 =Ceramic $0.1\mu\text{F}$, Ripple= 0.2Vp-p , $T_{\text{opt}}=25^\circ\text{C}$)



RP173x30xx

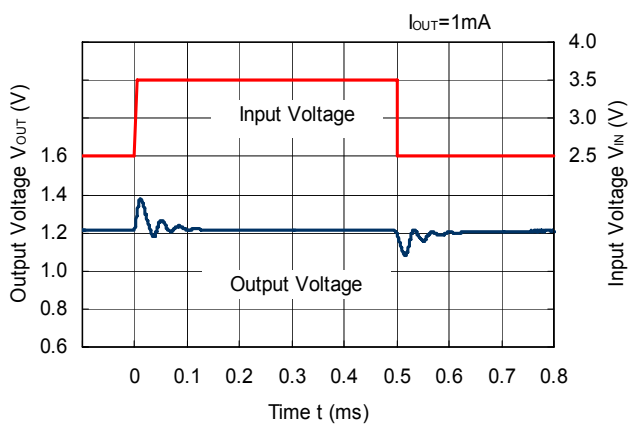


RP173x55xx

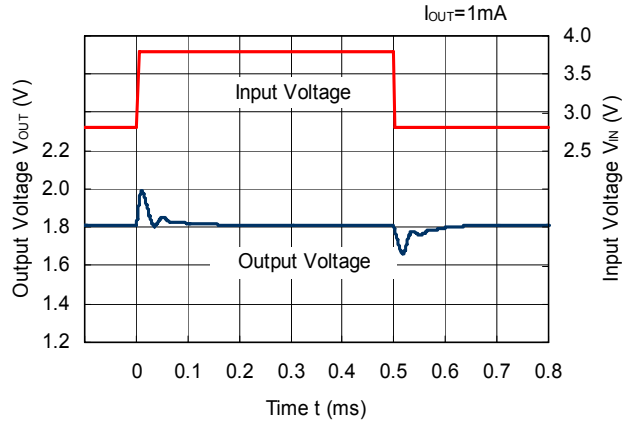


10) Input Transient Response ($C1=none$, $C2=Ceramic\ 0.1\mu F$, $t_r=t_f=5.0\mu s$, $T_{opt}=25^{\circ}C$)

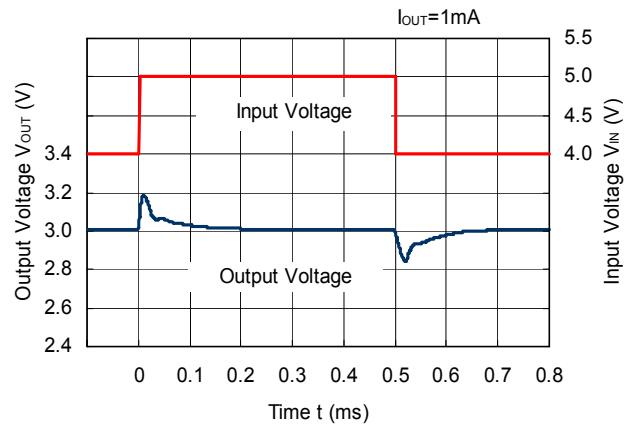
RP173x12xx



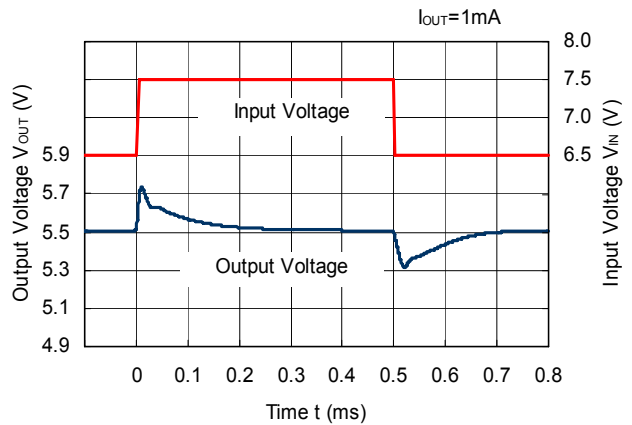
RP173x18xx



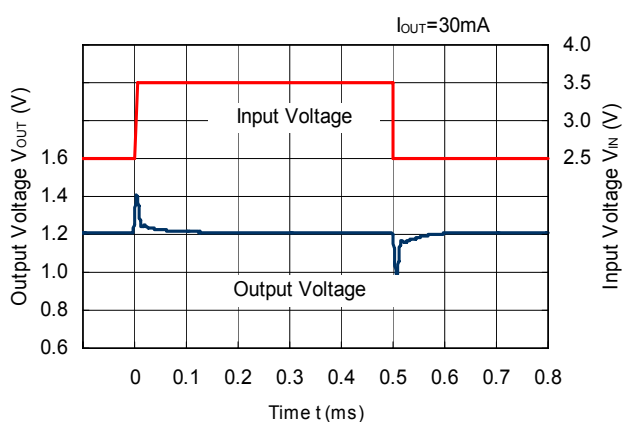
RP173x30xx



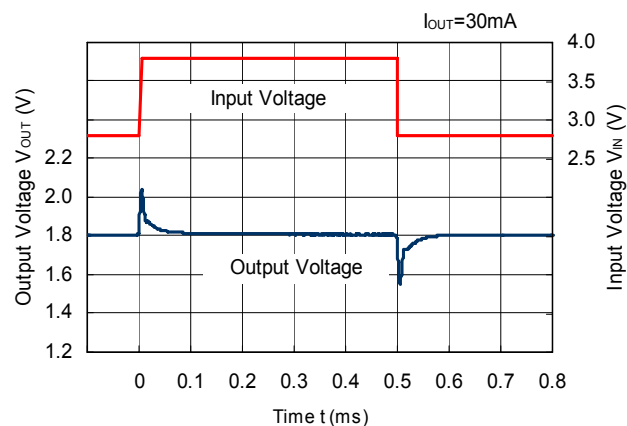
RP173x55xx



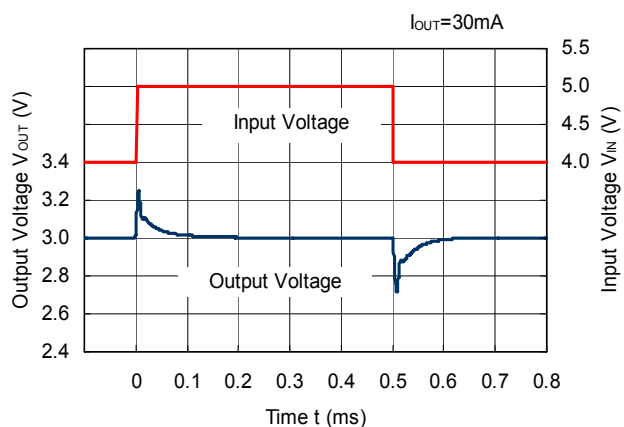
RP173x12xx



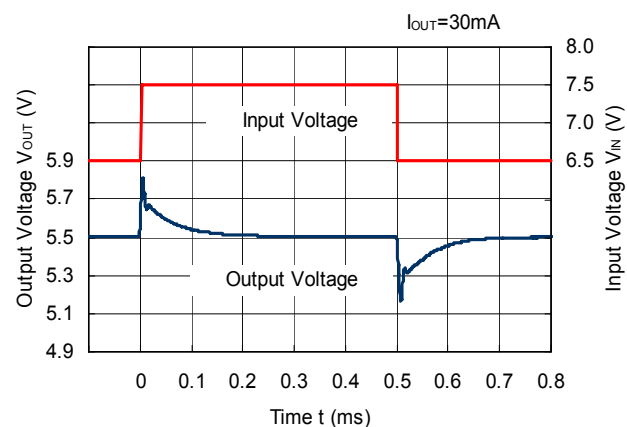
RP173x18xx



RP173x30xx

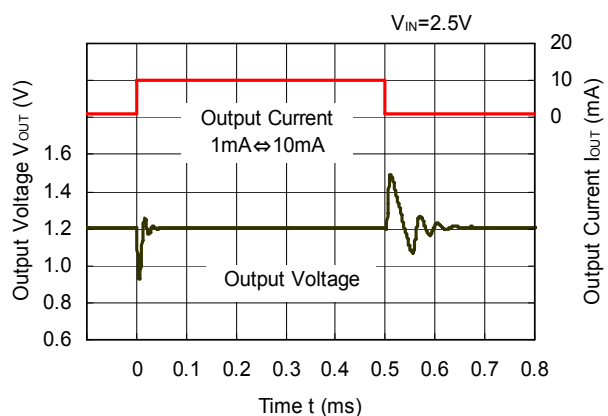


RP173x55xx

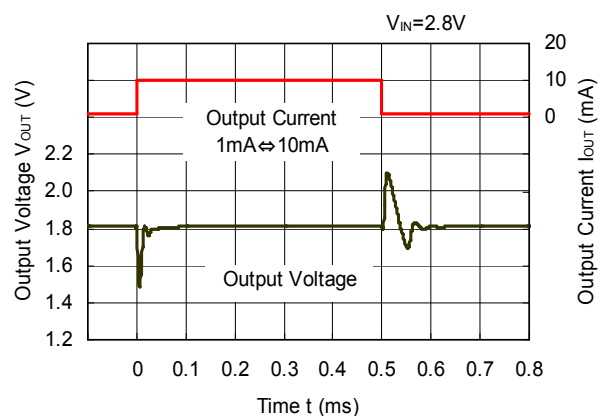


11) Load Transient Response ($C1$ =Ceramic $0.1\mu F$, $C2$ =Ceramic $0.1\mu F$, $t_r=t_f=0.5\mu s$, $T_{opt}=25^\circ C$)

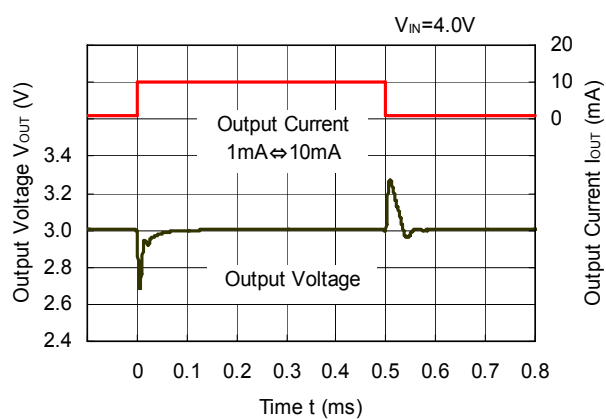
RP173x12xx



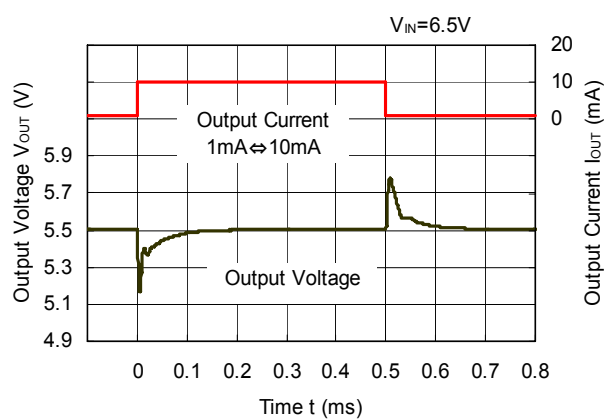
RP173x18xx



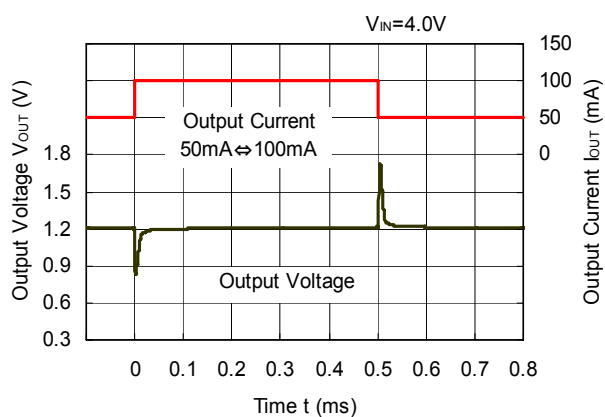
RP173x30xx



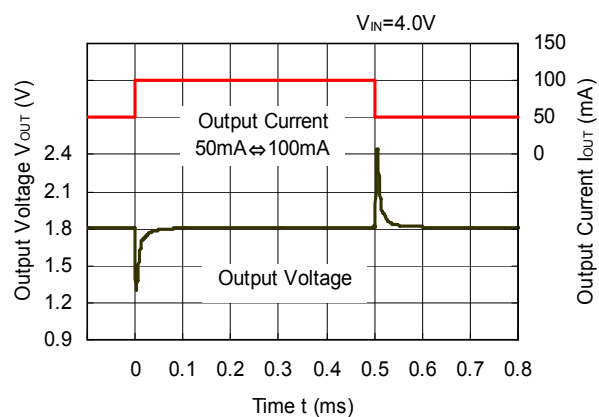
RP173x55xx



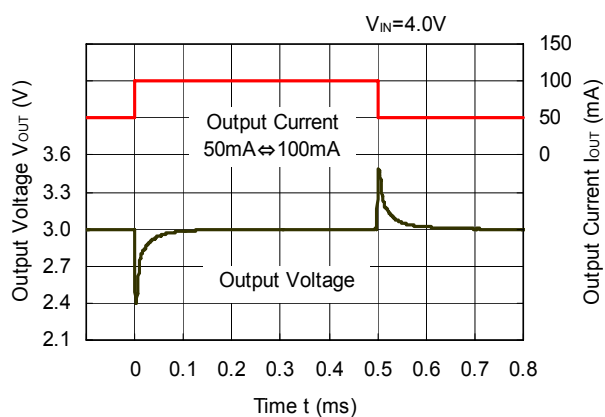
RP173x12xx



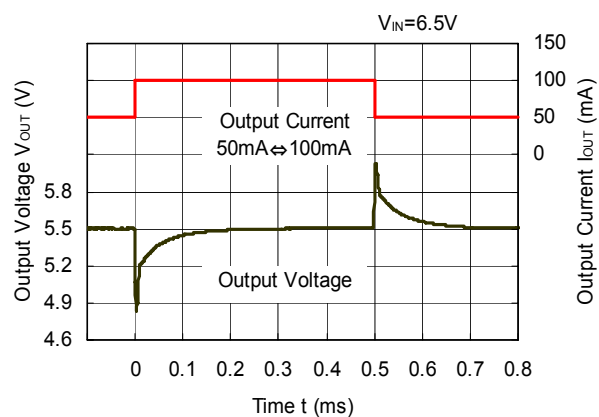
RP173x18xx



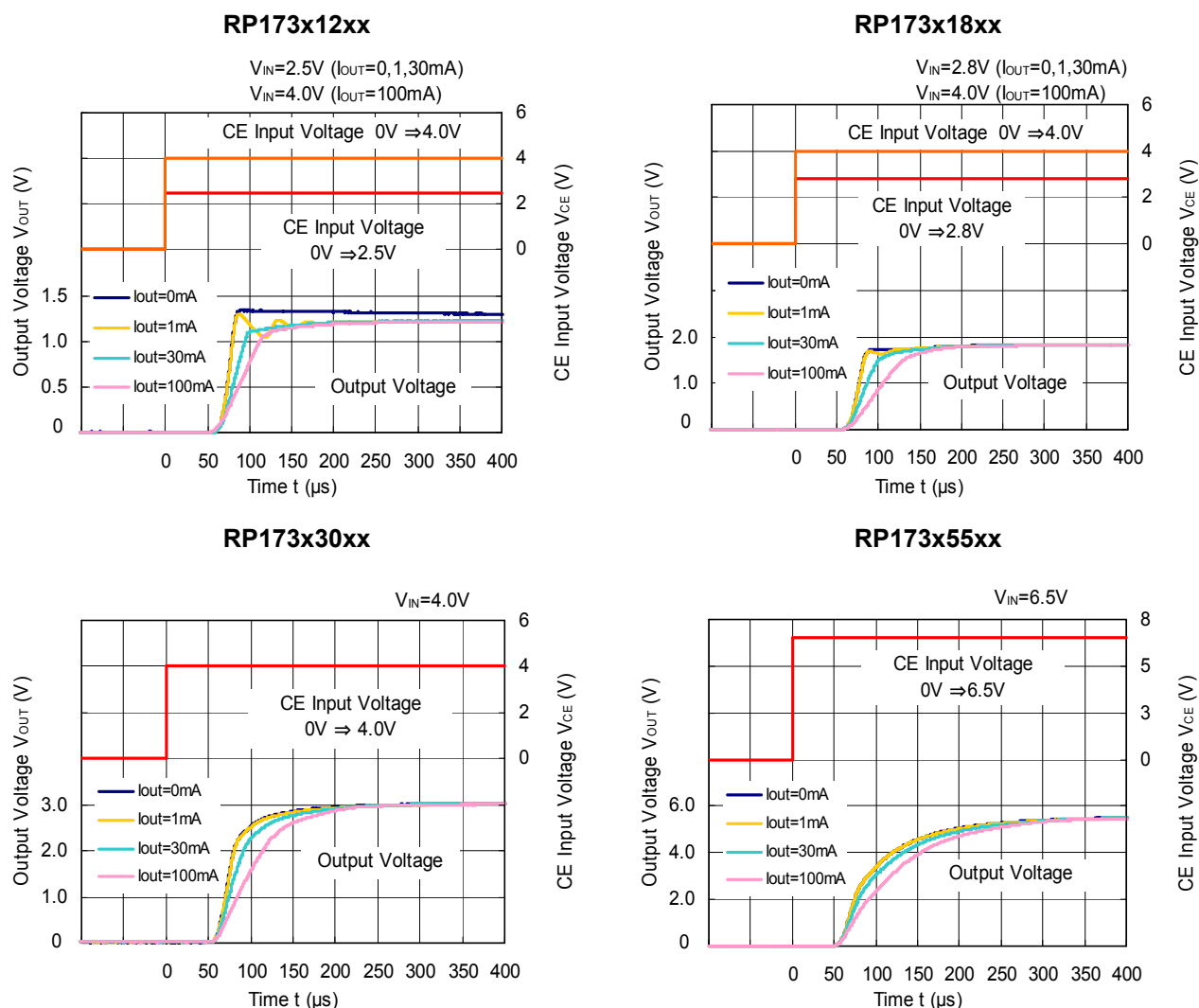
RP173x30xx



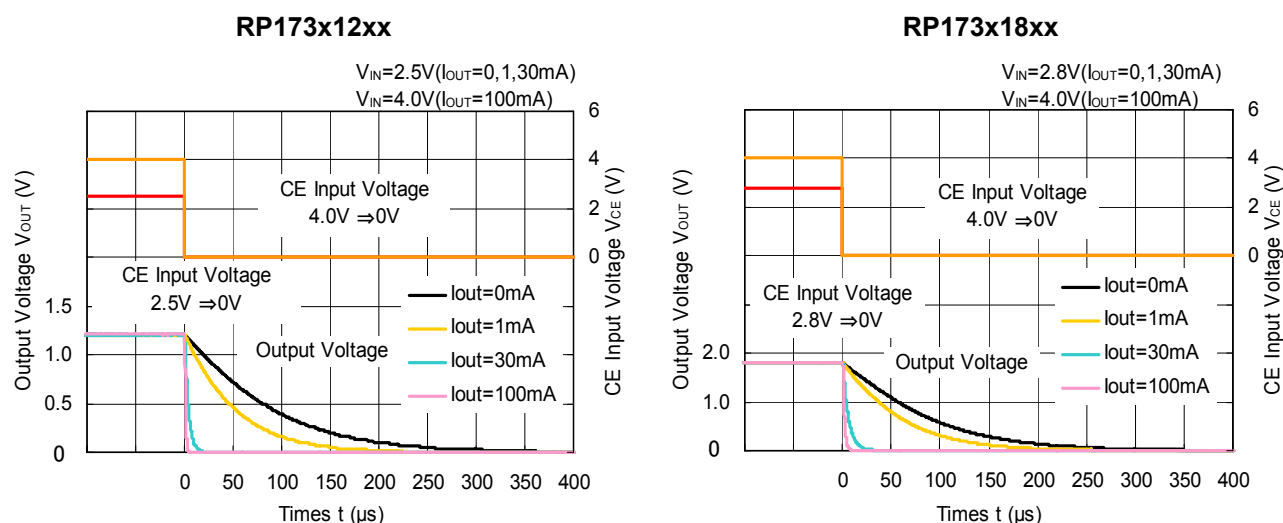
RP173x55xx



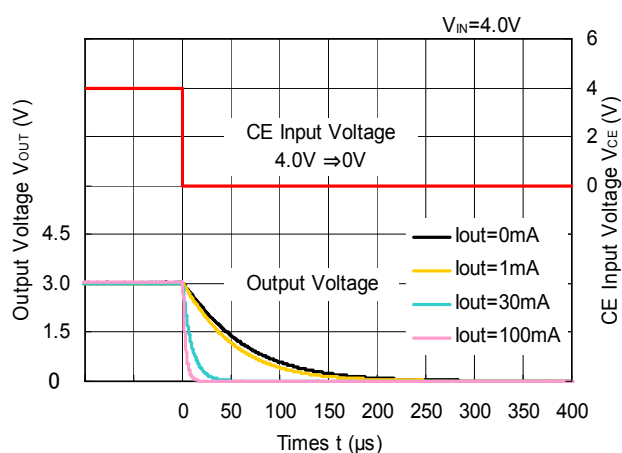
12) Turn on Speed (C1=Ceramic 0.1 μ F, C2=Ceramic 0.1 μ F, T_{opt}=25°C)



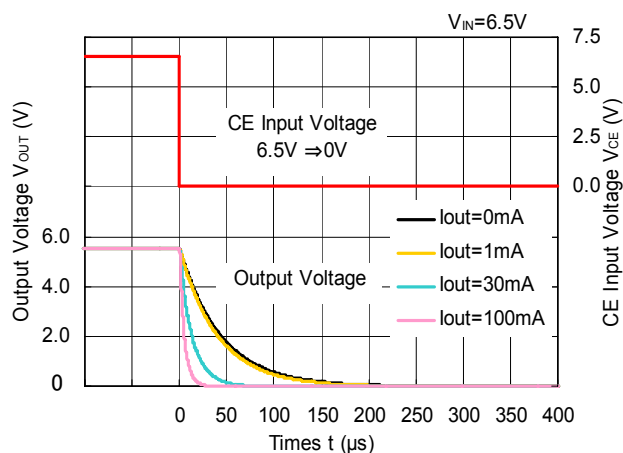
13) Turn off Speed with CE pin (C1=Ceramic 0.1 μ F, C2=Ceramic 0.1 μ F, T_{opt}=25°C)



RP173x30xx



RP173x55xx



ESR vs. Output Current

When using these ICs, consider the following points: The relations between I_{OUT} (Output Current) and ESR of an output capacitor are shown below. The conditions when the white noise level is under 40 μ V (Avg.) are marked as the hatched area in the graph.

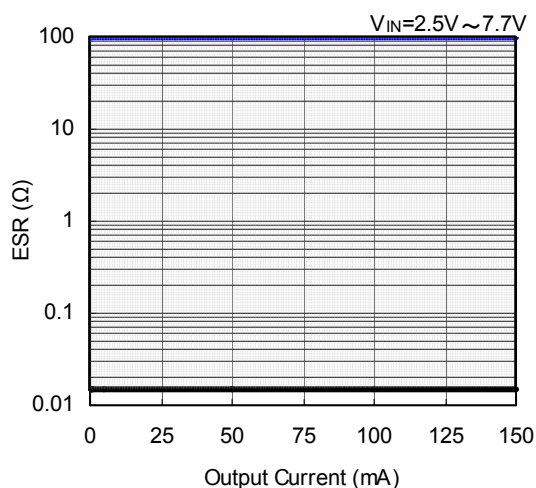
Measurement Conditions

Frequency Band : 10Hz to 2MHz

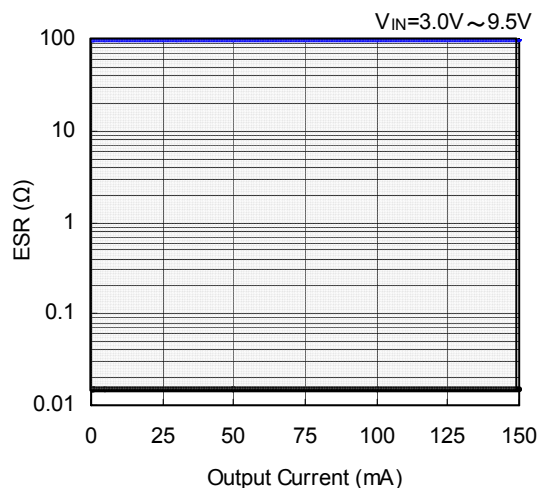
Temperature : -40 $^{\circ}$ C to 85 $^{\circ}$ C

C1,C2 : 0.1 μ F

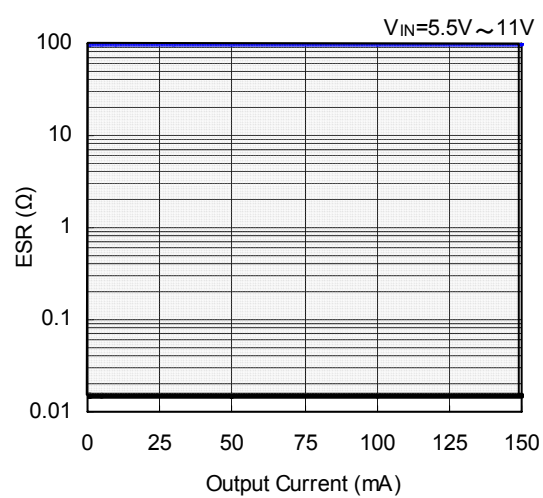
RP173x0121x



RP173x301x



RP173x551x





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■ Ricoh awarded ISO 14001 certification.

The Ricoh Group was awarded ISO 14001 certification, which is an international standard for environmental management systems, at both its domestic and overseas production facilities. Our current aim is to obtain ISO 14001 certification for all of our business offices.

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Ricoh completed the organization of the Lead-free production for all of our products. After Apr. 1, 2006, we will ship out the lead free products only. Thus, all products that will be shipped from now on comply with RoHS Directive.